

1N483B

Small Signal Diode



DO-35

Absolute Maximum Ratings * T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Unit	
V _{RRM}	Maximum Repetitive Reverse Voltage	80	V	
I _{F(AV)}	Average Rectified Forward Current	200	mA	
I _{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 4.0	A A	
T _{STG}	Storage Temperature Range	-65 to +200	°C	
T _J	Operating Junction Temperature	175	°C	

 $^{^{\}star}$ These ratings are limiting values above which the serviceability of the diode may be impaired.

NOTES

Thermal Characteristics

Symbol	Parameter	Value	Unit	
P_{D}	Power Dissipation	500	mW	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	300	°C/W	

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max	Units
V _R	Breakdown Voltage	I _R = 100μA	80		V
V _F	Forward Voltage	I _F = 100mA		1.0	V
I _R	Reverse Leakage	V _R = 60V V _R = 60V, T _A = 150°C		25 5	nA μA

¹⁾ These ratings are based on a maximum junction temperature of 200 degrees C.

²⁾ These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition		
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.		
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Rev. I15





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Product status/pricing/packaging

BUY

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
1N483B	Full Production	Full Production	\$0.023	DO-35	2		<u>Line 1:</u> \$Y (Fairchild logo) <u>Line 2:</u> 1N <u>Line 3:</u> 48 <u>Line 4:</u> 3B
1N483BTR	Full Production	Full Production	\$0.023	DO-35	2		<u>Line 1:</u> \$Y (Fairchild logo) <u>Line 2:</u> 1N <u>Line 3:</u> 48 <u>Line 4:</u> 3B

^{*} Fairchild 1,000 piece Budgetary Pricing

Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product 1N483B is available. Click here for more information.

^{**} A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples

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